



Questions About IEC 62108 Implementation

NREL PV Module Reliability Workshop

Mike Ludowise, Feb. 18-19, 2010



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Outline



- Introduction
 - Intent of 62108 – “Concentrator Photovoltaic (CPV) Modules and Assemblies - Design Qualification And Type Approval”
 - Brief History

- Experience in Implementing 62108 from an HCPV manufacturer’s viewpoint
 - Design variations
 - Inappropriate cell tests
 - Vague directions, desired additions
 - Other Issues

- Conclusions & Questions

From the viewpoint of a newcomer in CPV interested in applying the standard in a balanced way within an industrial setting, but without the benefit of silicon PV experience.

Introduction

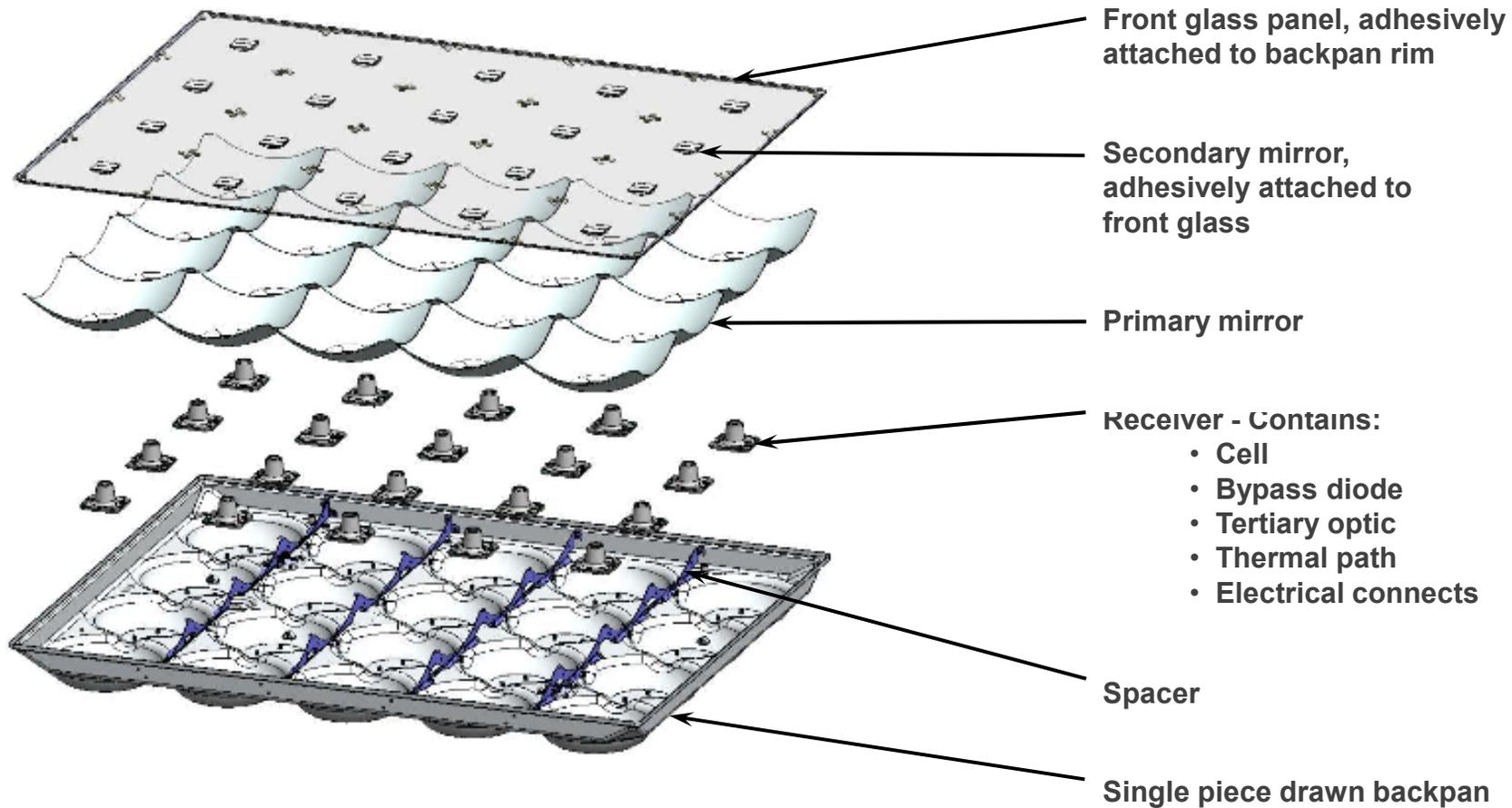


- Intent of 62108
 - To specify the minimum requirements for the design qualification and type approval of concentrator photovoltaic (CPV) modules and assemblies and receivers

- History
 - IEEE 1513 issued in 2001 as first CPV standard
 - Started in 1997, NREL led effort
 - Expired in 2006
 - Served as first draft of IEC 62108
 - IEC 62108 issued in 2007 as comprehensive CPV standard
 - Started in 2000, NREL led effort
 - Influenced by IEC 61215, “Design Qualification and Type Approval” aimed at flat plate terrestrial crystalline silicon PV modules

- Few HCPV system fabricators in 2002
 - HCPV is still a nascent branch of the PV industry
 - 2007 marked the entry of many companies into the HCPV space
 - Experience is “testing” 62108 against real world realities:
 - Widely varied HCPV system designs
 - Application to contemporary HCPV III-V cells
 - Tight funding, budget, and time-to-market constraints

Parts Identification - Module Assembly



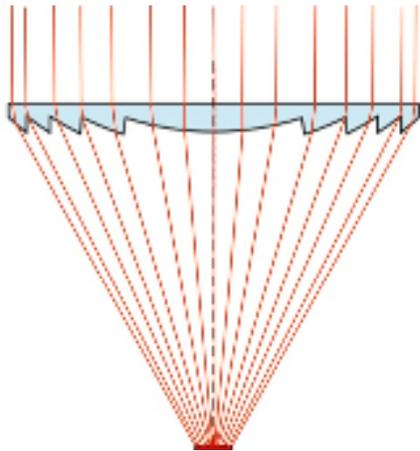
SolFocus SF1100 Panel

Two of Many Designs



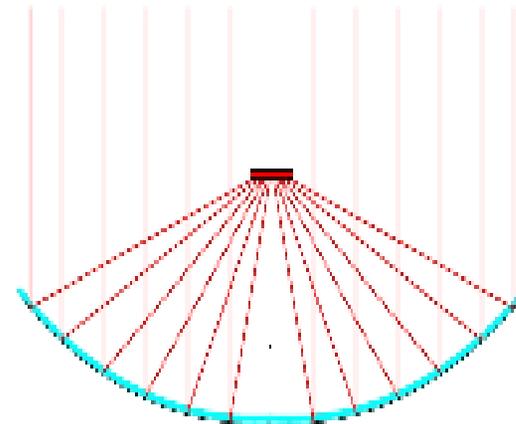
Two Fundamental Approaches

- Refractive: with lenses



Amonix, California

- Reflective: with mirrors



Solar Systems, Australia

Thermal Cycle Test



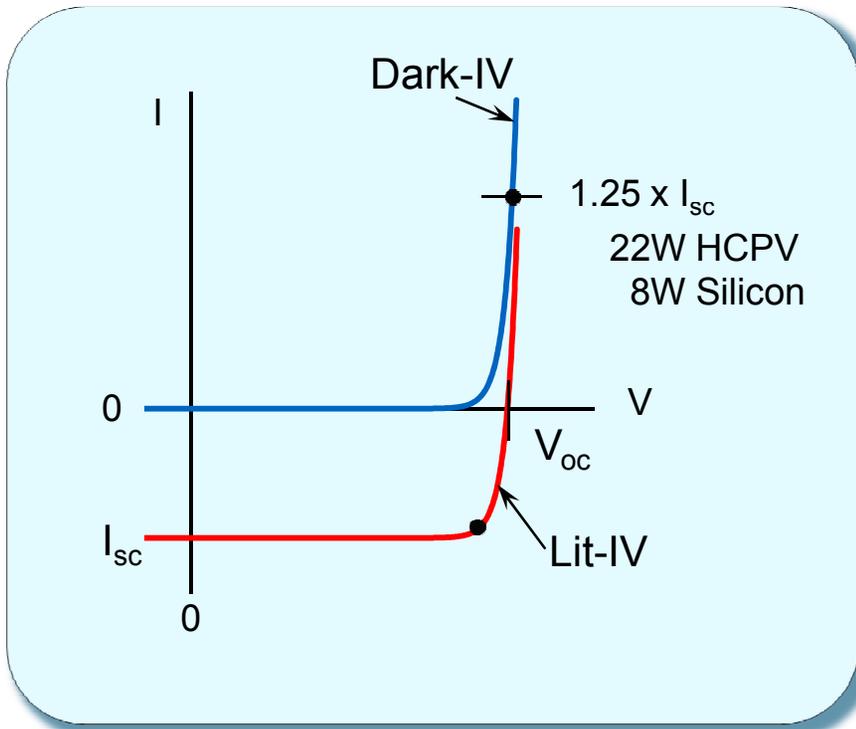
- Section 10: current cycling in the hi-T parts of thermal cycle test using one of:
 - a) Driving the cell to $1.25 \times I_{sc}$ forward current using an external DC source
 - b) Illuminating with full intensity light to generate $1.25 \times I_{sc}$
 - c) Partial illumination combined with an external drive to generate $1.25 \times I_{sc}$
- Pass:
 - No major visual defects
 - No interruption of current flow during the test
 - Insulation resistance passes per clause 10.4.
- Notes the above may be detrimental to cells – provides alternate and additional test:
 - Retain option a) above with no applied current
 - Drive additional “dead” cells to $1.25 \times I_{sc}$ such that $\Delta T_{test} \geq \Delta T_{operation}$
 - Simulates operational thermal mismatch, fatigue, other stresses
 - Additional receivers pass $\Delta R_{receiver} < 2\%$ (excluding the cell).
- Attempts to simulate on-sun stresses; tests the die attach bond line integrity, solder, and electrical connection reliability

Dark IV and Light IV Comparison



Driven $1.25 \cdot I_{sc}$ pushes the cell to a different operating point beyond the intended design range

Flat silicon conditions do not translate directly to III-V HCPV cells



Silicon @ 1-sun

$V_{oc} = \sim 1V$
 $I_{sc} = 6A$ (150cm² cell)
 $J_{sc} = 40mA/cm^2$
 $P = 40mW/cm^2$
 $P = 6W$

$1.25 \cdot J_{sc} = 50mA/cm^2$
 Monolithic

III-V HCPV Cell

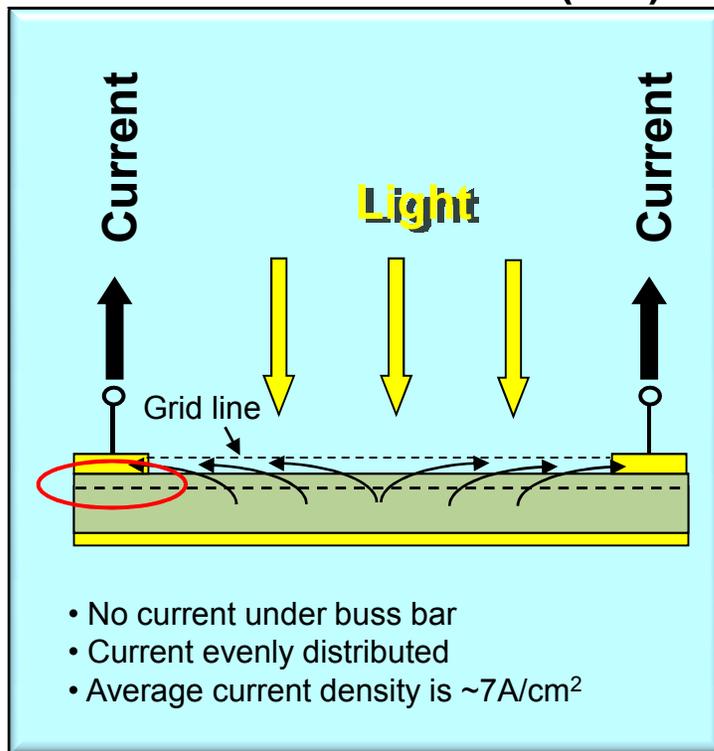
$V_{oc} = \sim 3V$
 $I_{sc} = 6A$ (1cm² cell)
 $J_{sc} = 6A/cm^2$
 $P = 17W/cm^2$
 $P = 17W$

$1.25 \cdot J_{sc} = 7.6A/cm^2$
 Epitaxial Construction

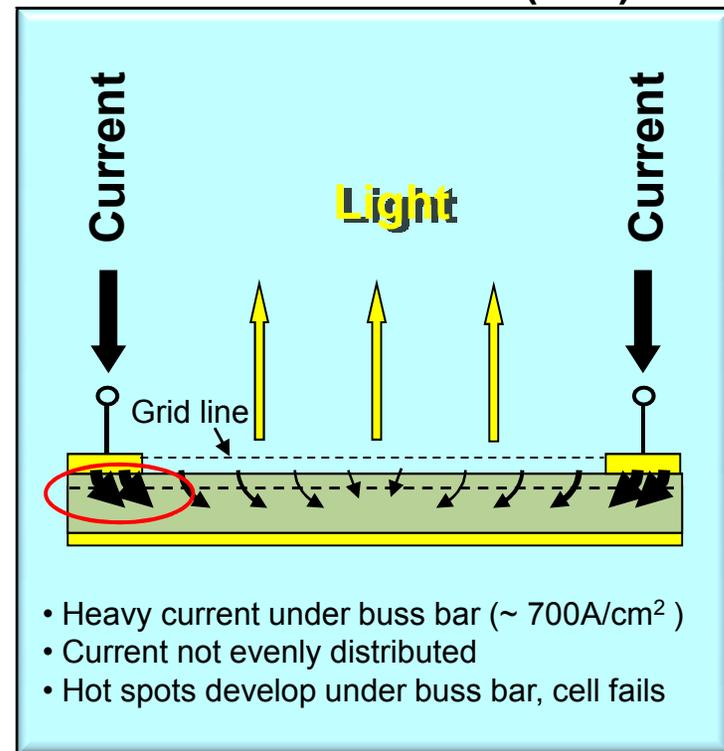
DIV vs LIV Stress



Illuminated Drive (LIV)



External Drive (DIV)



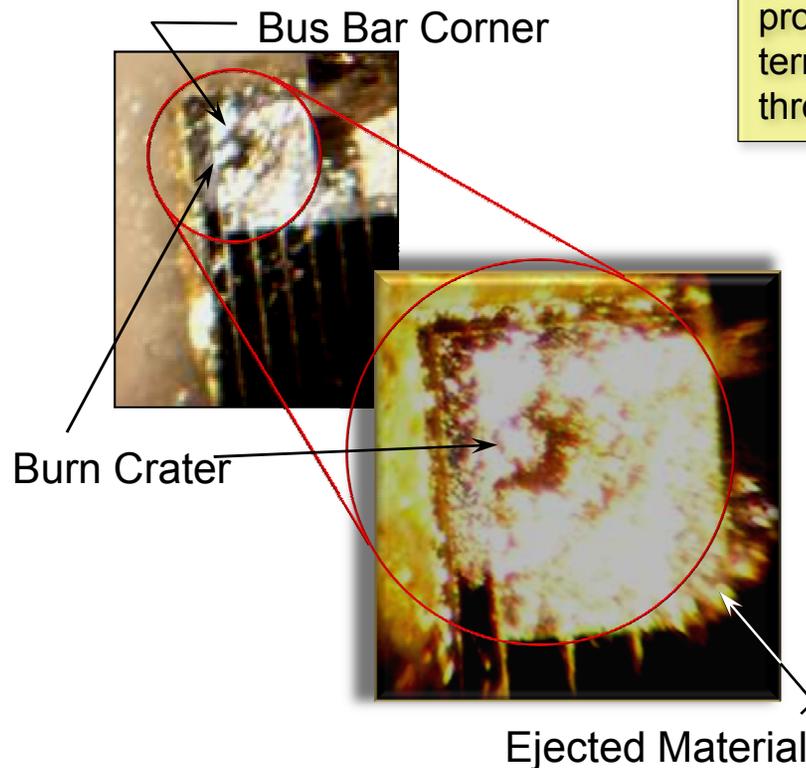
- Any small defects under the buss bar concentrate forward current
- Thermal run-away results

Cell Failures from Over-current Stress

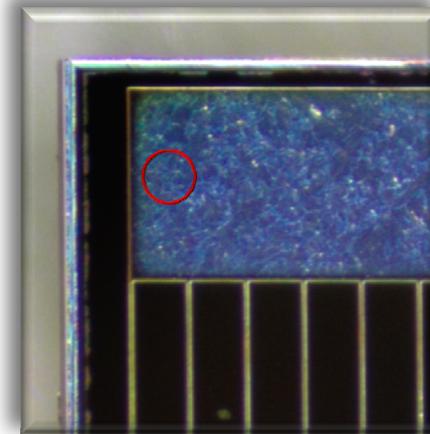


US 2004/0261838 A1

[0012] ... the cause of the current limitation and premature failure of ... cells ... is the result of the heat produced by tiny local current shunts (sometimes termed "filaments") that short the metallic busbar layer through the underlying semiconductor material ...



Burned Out Cell



New Cell

Currents as low as ~4A have been observed to damage cells -

Vague Sections



■ Section 9: Modifications

- “Any changes in design, materials, components, or processing of the modules and assemblies may require a repetition of some or all of the qualification tests to maintain type approval. Manufacturers shall report to and discuss with the certifying body and testing agency every change they made.”
- Is the testing agency the best authority to make these decisions?
- For example, sourcing cells from an alternate supplier:
 - Is there a way to handle identical form, fit and function cells from alternate manufacturers without triggering a re-test?
 - If the cell V_{oc} increases? Internal epi composition change? IMM Cells?
- Is it more sensible for the IEC standard to be expanded to include major categories of changes that trigger re-testing, and specify the test section affected.

Other Issues Worth Addressing



- Cycle time for the full IEC 62801 tests suite is 6 to 9 months
 - Similar flat plate exposure is only about 3 months
 - Long term outdoor & UV exposure pace the tests; 1000kWhrs DNI required
 - Result: ~1yr. to certify against IEC 62108
 - CPV market and technology moves rapidly
 - Difficult for CPV to overcome cycle time handicaps
 - Valuable time to market can be lost owing to small changes
- Hundreds of thousands of dollars may be spent in the process
- Develop field data correlation to accelerated tests of IEC 62108
 - Standards may not identify all degradation modes
 - If CPV cells operate in hot, dry climates, 85°C/85% RH may be overkill
 - UV degradation of index-matching silicones not yet correlated with on-sun exposure
 - Humidity Freeze test does not necessarily mimic stresses found at any location on earth

Other Possible Revisions



- Thermal Cycling:
 - Probably cycles too slowly
 - 18 cycles/day => ~5C/min.
 - OK for 1-sun system, but slow for high intensity systems with rapid $\Delta T/\Delta t$
 - May result in under-testing of the receiver assembly

- Carry over test from flat panel
 - Tests carried over from flat panel should be consistent with flat-panel standards
 - E.g., flat panel humidity freeze is 10 cycles; 62108 requires 20 cycles

Beyond 62108



- Cell level testing
 - Reliability tests
 - Standards for cell interchangeability
- Enhanced outdoor exposure testing
 - Add a larger population requirement
 - Concentrated sunlight cannot be replicated in a chamber
 - Many degradation mechanisms unique to concentrated sunlight
 - Lends more confidence to customers, investors
- Pooled experience
 - CPV companies have collectively learned much about accelerated testing
 - Try to quantify tests in terms of years of field life
 - Differences in concentrator designs
 - Approximate accelerations for different component or material types would help
 - Quixotic hope of pooling knowledge base to enhance standards
- Vibration or mechanical shock testing
 - Shipping and installation damage
 - Well known correlations for adhesives to static system lifetimes

Questions



- What is the best method for simulating on-sun stresses during thermal cycle?
- How should new solar cells be introduced into the product under IEC 62108?
 - When is a re-test triggered, and when is it not?
 - Will solar cell qualification and reliability standards help?
- How to set uniform change thresholds for re-testing :
 - By sub-system, i.e. optics, cell, structural, electrical?
 - When substituted parts are “identical” without cross reference standards?

I would like to acknowledge the SolFocus staff, especially Mark Spencer, Steve Horne, and Nancy Hartsoch, and many others in the industry including Bob McConnell, Pete Hebert, Ian Aeby, James Foresi, Paul Lamarche, and Sarah Kurtz who shared their thoughts and comments on IEC 62108.